

54ACTQ32 Quiet Series Quad 2-Input OR Gate

General Description

The 'ACTQ32 contains four, 2-input OR gates and utilizes NSC Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series[™] features GTO[™] output control and undershoot corrector in addition to a split ground bus for superior ACMOS performance.

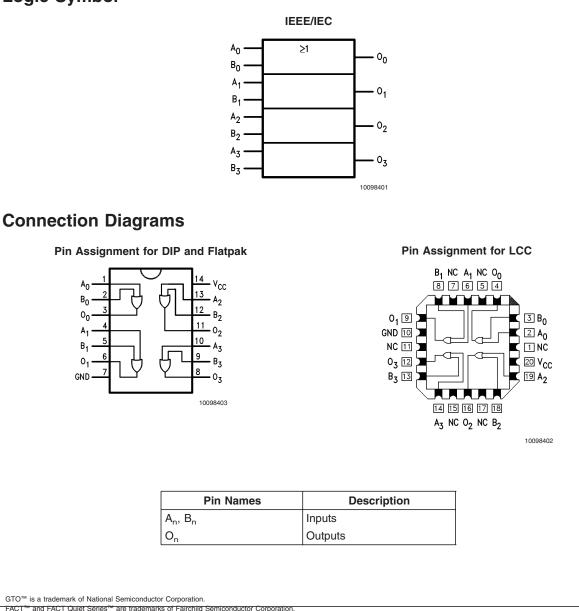
Guaranteed simultaneous switching noise level and dynamic threshold performance

- Improved latch-up immunity
- Outputs source/sink 24 mA
- 'ACTQ32 has TTL-compatible inputs
- Standard Microcircuit Drawing (SMD) 5962-8973601

Features

■ I_{CC} reduced by 50%

Logic Symbol



Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V _{CC})	–0.5V to +7.0V
DC Input Diode Current (I _{IK})	
$V_1 = -0.5V$	–20 mA
$V_1 = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V _I)	–0.5V to V _{CC} + 0.5V
DC Output Diode Current (I _{OK})	
$V_{O} = -0.5V$	–20 mA
$V_{\rm O} = V_{\rm CC} + 0.5 V$	+20 mA
DC Output Voltage (V _O)	–0.5V to V _{CC} + 0.5V
DC Output Source	
or Sink Current (I _O)	±50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	–65°C to +150°C

Junction Temperature (T_J) CDIP

175°C

Recommended Operating Conditions

Supply Voltage (V _{CC})	
'ACTQ	4.5V to 5.5V
Input Voltage (V _I)	0V to $V_{\rm CC}$
Output Voltage (V _O)	0V to $V_{\rm CC}$
Operating Temperature (T _A)	
54ACTQ	–55°C to +125°C
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
'ACTQ Devices	
V _{IN} from 0.8V to 2.0V	
V _{CC} @ 4.5V, 5.5V	125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT[™] circuits outside databook specifications.

DC Characteristics for 'ACTQ Family Devices

			54ACTQ		Conditions
Symbol	Parameter	V _{cc}	T _A =	Units	
		(V)	–55°C to +125°C		
			Guaranteed Limits	1	
V _{IH}	Minimum High Level	4.5	2.0	V	V _{OUT} = 0.1V
	Input Voltage	5.5	2.0		or V _{CC} – 0.1V
V _{IL}	Maximum Low Level	4.5	0.8	V	$V_{OUT} = 0.1V$
	Input Voltage	5.5	0.8		or V _{CC} – 0.1V
V _{он}	Minimum High Level	4.5	4.4	V	I _{OUT} = -50 μA
	Output Voltage	5.5	5.4		
					(Note 2)
					$V_{IN} = V_{IL} \text{or } V_{IH}$
		4.5	3.70	V	I _{он} = –24 mA
		5.5	4.70		I _{ОН} = –24 mA
V _{OL}	Maximum Low Level	4.5	0.1	V	Ι _{ΟUT} = 50 μΑ
	Output Voltage	5.5	0.1		
					(Note 2)
					$V_{IN} = V_{IL} \text{or } V_{IH}$
		4.5	0.50	V	I _{OL} = 24 mA
		5.5	0.50		I _{OL} = 24 mA
I _{IN}	Maximum Input	5.5	±1.0	μA	$V_1 = V_{CC}, GND$
	Leakage Current				
I _{CCT}	Maximum	5.5	1.6	mA	$V_{I} = V_{CC} - 2.1V$
	I _{CC} /Input				
I _{old}	Minimum Dynamic	5.5	50	mA	V _{OLD} = 1.65V Max
I _{OHD}	Output Current (Note 3)	5.5	-50	mA	V _{OHD} = 3.85V Min
I _{cc}	Maximum Quiescent	5.5	80.0	μA	$V_{IN} = V_{CC}$
	Supply Current				or GND (Note 3)

Note 2: All outputs loaded; thresholds on input associated with output under test. **Note 3:** Maximum test duration 2.0 ms, one output loaded at a time.

AC Electrical Characteristics

Symbol	Parameter	V _{cc} (V) (Note 4)	54ACTQ T _A = -55°C to +125°C C _L = 50 pF		Units	Fig. No.
			Min	Мах		
t _{PLH}	Propagation Delay	5.0	1.5	7.5	ns	
t _{PHL}	Propagation Delay	5.0	1.5	7.5	ns	

Note 4: Voltage Range 5.0 is 5.0V $\pm 0.5V$

Capacitance

Symbol	Parameter	Max	Units	Conditions
C _{IN}	Input Capacitance	10.0	pF	$V_{CC} = OPEN$
C _{PD}	Power Dissipation	72.0	pF	$V_{\rm CC} = 5.0 V$
	Capacitance			

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